

# PulseForge Achieves Sub-10 $\mu\text{m}$ Silicon Breakthrough in Ultra-Thin Wafer Processing with Photonic Debonding

*Advancement surpasses industry benchmarks from Intel (~19  $\mu\text{m}$ ), Infineon Technologies (~20  $\mu\text{m}$ ), and Resonac (~25  $\mu\text{m}$ )*

AUSTIN, TX, UNITED STATES, April 13, 2026 /EINPresswire.com/ -- [PulseForge](#), Inc., a leader in



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*Jonathan Gibson, CEO of PulseForge, Inc.*

advanced electronics manufacturing solutions, today announced a major breakthrough in semiconductor manufacturing: successful [photonic debonding](#) of next-generation memory architectures fabricated on ultra-thin silicon wafers below 10  $\mu\text{m}$ . This milestone was achieved in collaboration with a leading Korean memory manufacturer.

This achievement builds on prior demonstrations with the same customer, where PulseForge enabled reliable debonding at less than 20  $\mu\text{m}$  and 15  $\mu\text{m}$  wafer thicknesses. The latest result at less than 10  $\mu\text{m}$  represents

a significant leap forward, addressing one of the most critical barriers in advanced semiconductor manufacturing: handling and debonding ultra-fragile wafers without compromising yield or device integrity.

As the semiconductor industry pushes toward thinner wafers to unlock performance and efficiency gains, PulseForge has now extended the frontier well beyond current published benchmarks:

- ~25  $\mu\text{m}$  — Resonac (IEEE ECTC 2025 presentation) [1]
- ~20  $\mu\text{m}$  — Infineon Technologies (press release by Infineon) [2]
- ~19  $\mu\text{m}$  — Intel (press release by Intel) [3]
- ~8  $\mu\text{m}$  — PulseForge (2026, latest demonstration)

Reducing wafer thickness is a key lever for performance. For example, thinning to ~20  $\mu\text{m}$  has been shown to reduce substrate resistance by up to 50% and power losses by more than 15%. At the system level, these electrical improvements translate directly into more energy-efficient AI data centers—enabling lower power consumption per compute operation, improved thermal

management, and higher performance per watt across large-scale GPU and HBM deployments. PulseForge's demonstration at less than 10  $\mu\text{m}$  pushes into a regime previously considered impractical due to extreme wafer fragility, warpage, and yield risks.

The ability to reliably debond at sub-10  $\mu\text{m}$  thickness enables transformative advancements across multiple markets:

#### Advanced Memory (HBM, DRAM, NAND)

- Enables ultra-thin die stacking for next-generation HBM
- Increases bandwidth and improves thermal performance
- Supports scaling for AI and high-performance computing

#### Logic & Advanced Packaging

- Enables 3D integration, chiplets, and hybrid bonding
- Reduces interconnect length for improved latency and performance
- Supports wafer-to-wafer and die-to-wafer stacking

#### Power Semiconductors

- Reduces conduction losses and substrate resistance
- Enables thinner, higher-efficiency devices
- Supports electrification and AI data center power demands

PulseForge's photonic debonding platform is uniquely suited for ultra-thin wafer processing at scale:

- Superior yield at extreme thinness - Non-contact, low-stress debonding process eliminates wafer breakage below 10  $\mu\text{m}$  and preserves device integrity
- Reusable LAL-coated carriers - Enables multiple reuse cycles, significantly lowering consumable cost and improving sustainability
- Reduced cleaning requirements - Clean debond interface minimizes residue and simplifies post-process cleaning
- Best-in-class cost of ownership (COO) - Fewer process steps, high throughput, reduced footprint, and lower consumables drive compelling economics

Additionally, the process is adhesive-agnostic, allowing seamless integration into existing semiconductor manufacturing flows.

PulseForge has demonstrated capability across an industry-leading range of material thicknesses:

- ~0.7 nm — 2D material / TMDC transfer (imec collaboration)
- Less than 10  $\mu\text{m}$  — Silicon wafer debonding (latest milestone, advanced memory)
- Less than 20 and 15  $\mu\text{m}$  — Memory architectures (customer validation)

This breadth—from atomic-scale materials to production-scale wafers—highlights the precision,

scalability, and versatility of PulseForge's platform.

"Our collaboration with a leading Korean memory manufacturer demonstrates that photonic debonding is not just viable—but essential—for enabling sub-10 micron wafer processing," said Jonathan Gibson, CEO, PulseForge, Inc. He further added, "Our demonstration at ~8 microns establishes photonic debonding as a foundational technology for next-generation memory, logic, and power semiconductor manufacturing."

With accelerating demand for AI infrastructure, high-bandwidth memory, and advanced packaging, photonic debonding is emerging as a foundational technology for the semiconductor industry:

- HBM scaling for AI compute
- 3D heterogeneous integration and chiplet architectures
- Energy-efficient power electronics for data centers

PulseForge is uniquely positioned to bridge the gap between material innovation and high-volume semiconductor manufacturing, enabling the next wave of AI-driven performance scaling.

About PulseForge, Inc.

PulseForge, Inc. develops and manufactures state-of-the-art flashlamp-based tools that deliver energy in a precise and targeted manner to enable innovation in industrial manufacturing. Our expertise and tools empower our customers to explore novel materials and manufacturing methodologies, driving dynamic and efficient production at an industrial scale.

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